

Bis((dialkylamino)alkylselenolato)-metalcomplexes as precursors in the syntheses of metal selenide nanoparticles in [BMIm][BF₄]

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Metal chalcogenides

- **Various properties and applications**

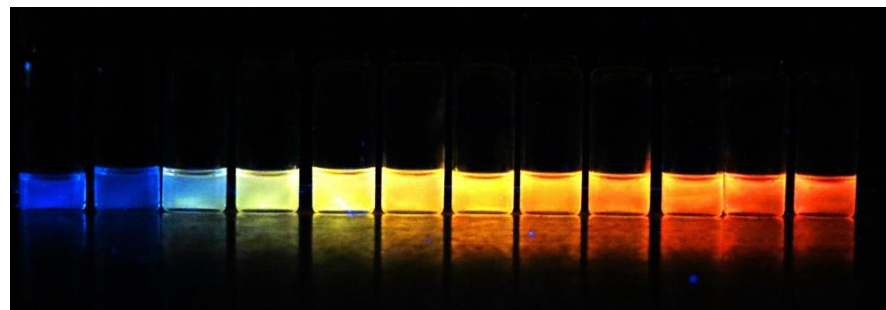
- Semiconductivity^[1,2,3,4]
- Nonlinear optical properties^[2]
- Superconductivity
- Electron tunneling^[2]
- Thermoelectrically properties
- Catalytic activity
- Solar cells^[1,3]
- Detector materials^[3]
- Photo resistors^[3]
- Telecommunication devices^[3,4]
- Switching elements
- Bioengineering^[4]

[1] Matthew L., *J. Chem. Ed.*, 2014, **91**, 274–279

[2] Sugimoto T.; *Elsevier*, Amsterdam, London, New York, 2001, 792

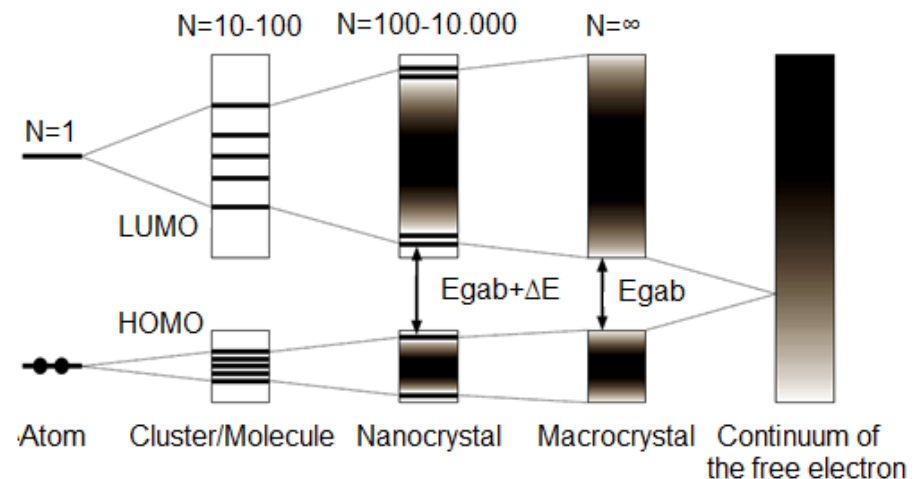
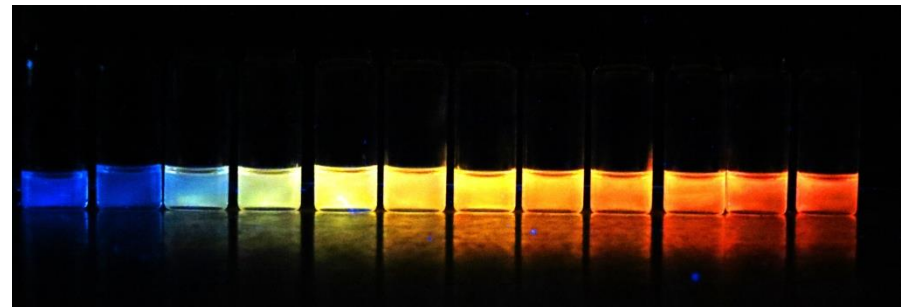
[3] J. Akhtar, J. C. Bruce et. al., *Mater. Res. Soc. Symp. Proc.* 2009, 1148-PP12-08

[4] N. Moloto, *Dissertation*, 2010, University of the Witwatersrand



Semiconductor nanocrystals

- Novel properties (electron tunneling, size quantization of energy levels ^[1,2]), result in applications in various fields (telecommunication systems, optoelectronics, IR detectors, solar cells, photorisors ^[3], catalysis and bioengineering)
- Discretization of the electronic energy levels beneath 7.6 nm (particle in the box)
- Hypsochromic shift of the absorption due to quantum confinement



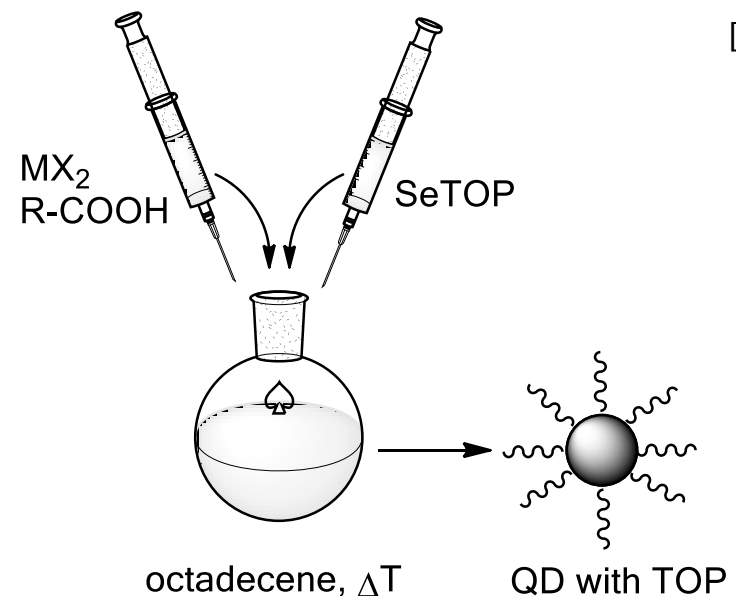
[1] Matthew L., *J. Chem. Ed.*, 2014, **91**, 274-279

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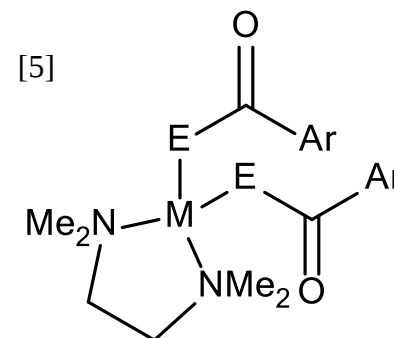
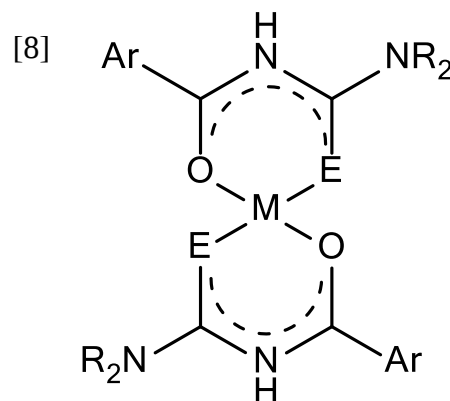
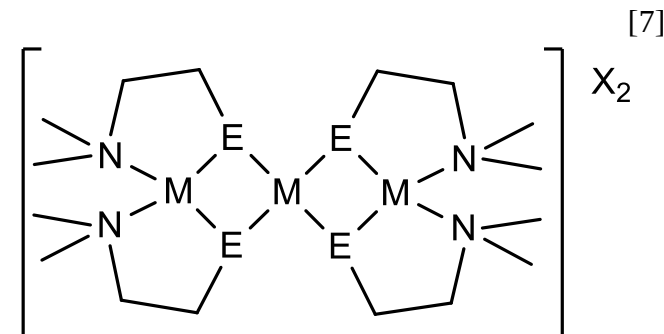
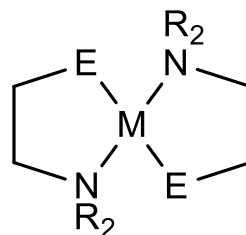
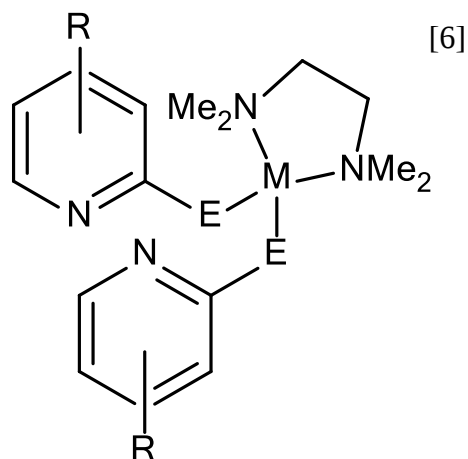
[3] J. Akhtar, J. C. Bruce et. al., *Mater. Res. Soc. Symp. Proc.* 2009, 1148-PP12-08

Hot Injection Method [1]

- In the classical synthesis metal chalcogenide quantum dots are produced by simultaneously injecting metal and selenium precursor solutions into a heated growth solution of octadecene
- The particle size can be varied by the reaction time and the temperature
- Usually these particles are stabilized by stabilizing agents such as hexadecylamine (HDA) or trioctylphosphine (TOP)



Single source precursors for metal chalcogenide nanoparticles



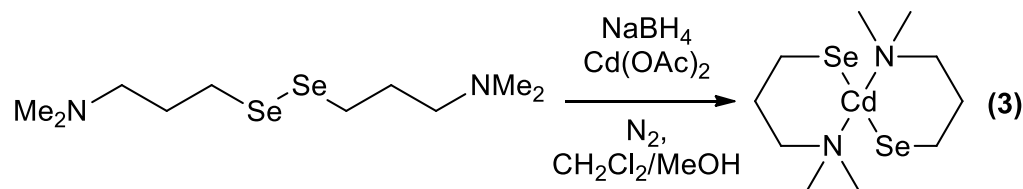
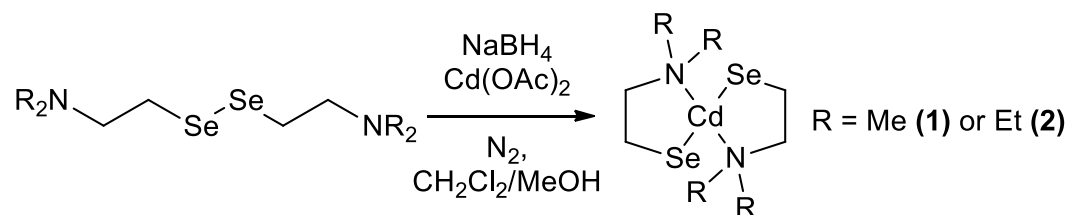
[5] V. K. Jain *et al.*, *Dalton Trans.*, 2006, 2714–2718

[6] V. K. Jain *et al.*, *Inorg. Chim. Ac.* 2011, **365**, 333–339

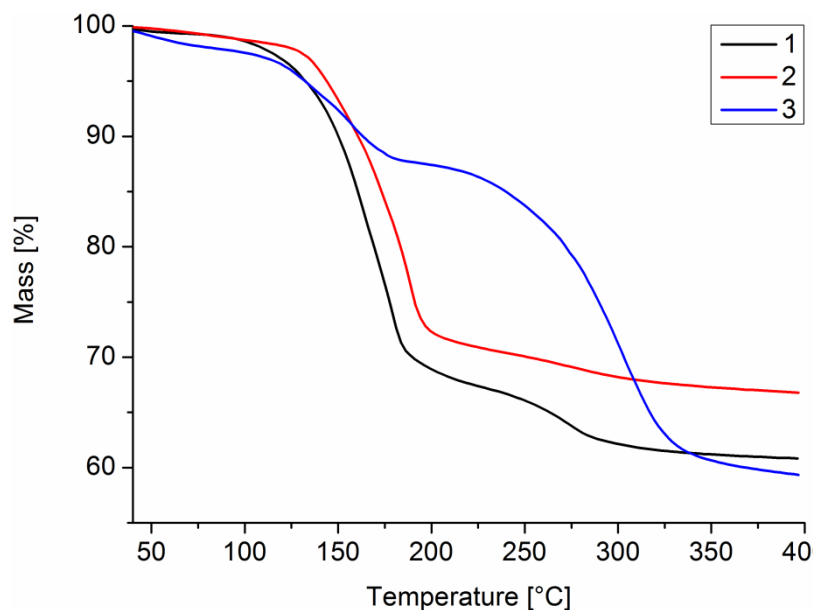
[7] V. K. Jain *et al.*; *Polyhedron* 2006, **25**, 2383–2391

[8] J. Akhtar, P. O'Brien *et al.*, *Eur. J. Inorg. Chem.* 2011, 2984–2990

CdSe NPs in [BMIm][BF₄]



[7]

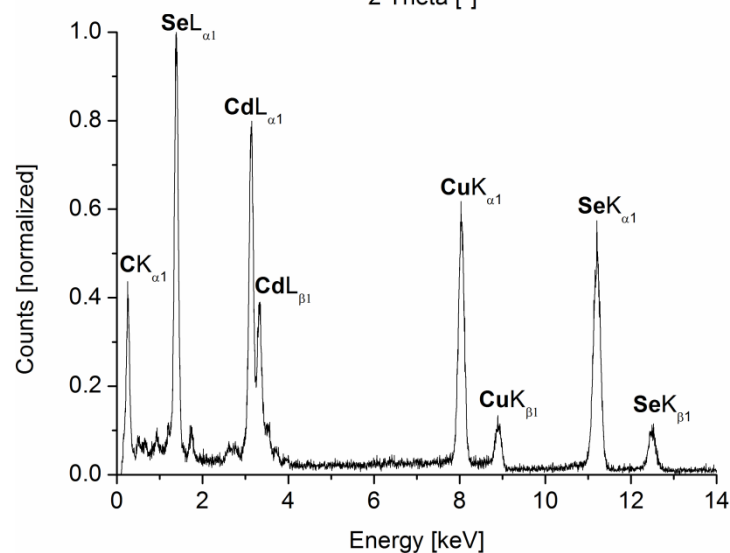
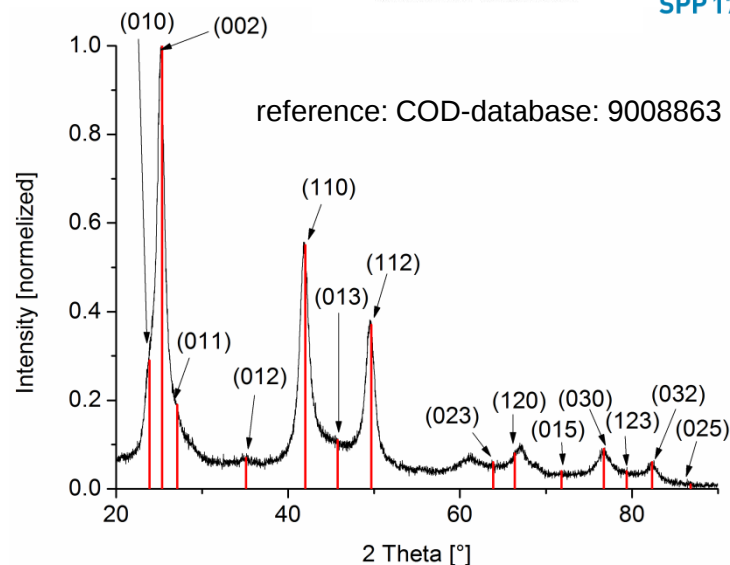
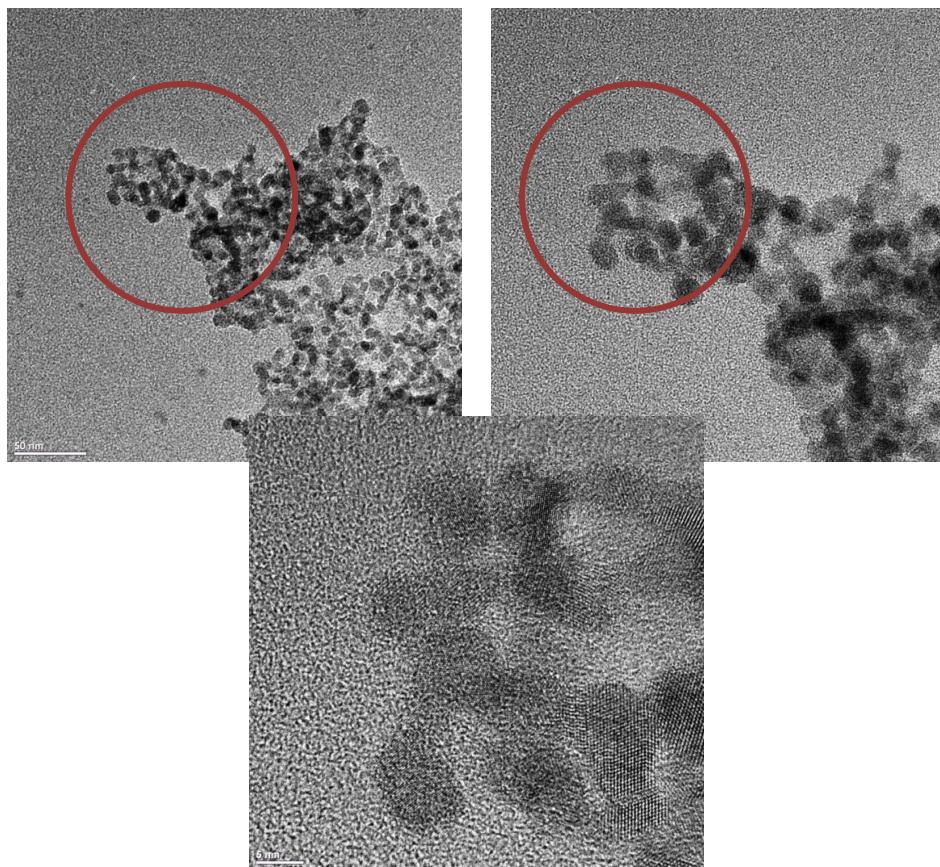
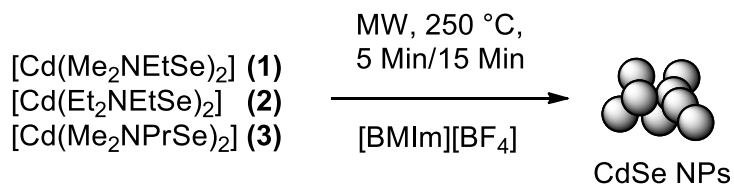


Precursor	Yield [%]	Δm [%]	$\Delta m_{\text{theor.}}$ [%]	Decomp. temp. [°C]	CdSe crystal system ^a
1	61	38	35	150	hexagonal P6 ₃ mc
2	42	39	39	165	hexagonal P6 ₃ mc
3	18	39	39	155	hexagonal P6 ₃ mc

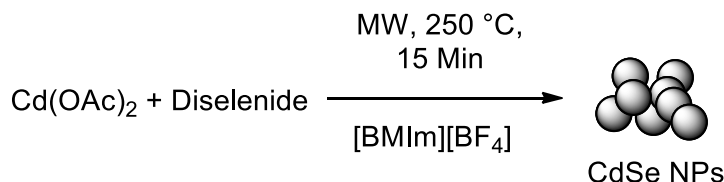
^a From PXRD analysis of the residue of the thermal analysis (hexagonal CdSe, reference: COD- database: 9008863).

[7] V. K. Jain *et al.*; *Polyhedron* 2006, **25**, 2383–2391

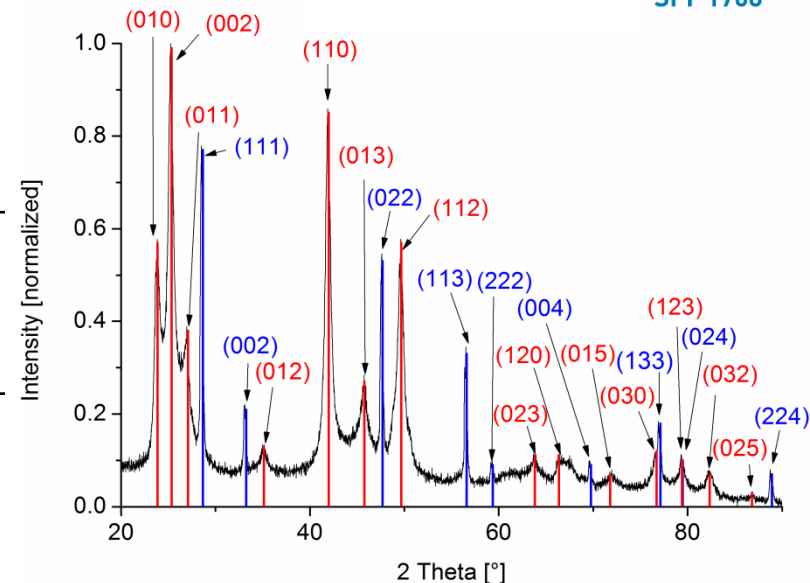
CdSe NPs in in [BMIm][BF₄]



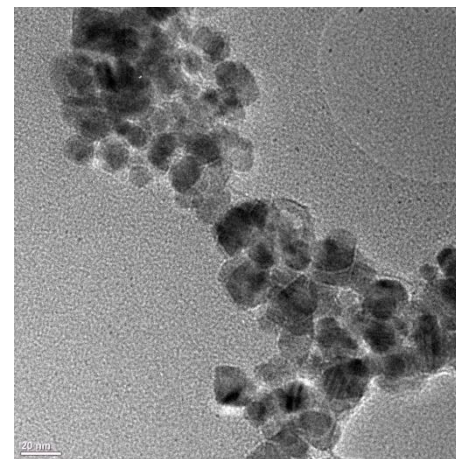
CdSe NPs in [BMIm][BF₄]



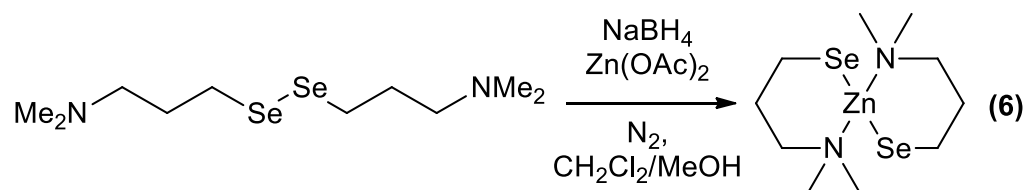
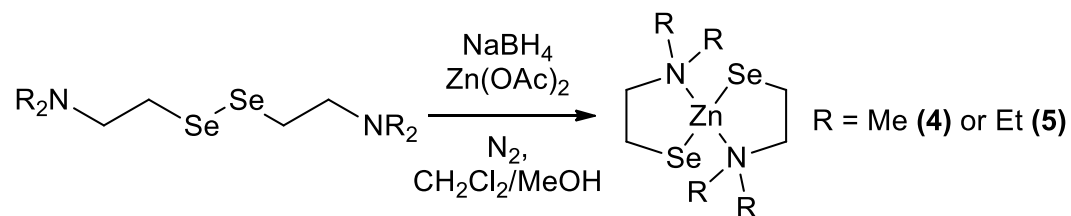
Precursor	NPs	Ø-NPs TEM [nm]	Ø-NPs PXRD [nm]	crystal system
1 (5min)	CdSe	20.0 ± 2.9	10.5 ± 1.3	hexagonal (P6 ₃ mc)
2 (5min)	CdSe	11.9 ± 2.5	8.0 ± 0.8	hexagonal (P6 ₃ mc)
3 (5min)	CdSe	9.3 ± 1.3	7.9 ± 0.7	hexagonal (P6 ₃ mc)
1 (15min)	CdSe	27.3 ± 3.5	8.0 ± 1.8	hexagonal (P6 ₃ mc)
2 (15 min)	CdSe	18.6 ± 2.9	9.6 ± 1.3	hexagonal (P6 ₃ mc)
3 (15 min)	CdSe	10.9 ± 1.7	7.8 ± 0.5	hexagonal (P6 ₃ mc)
Cd(OAc) ₂ + (Me ₂ NEtSe) ₂	CdSe + CdF ₂	-	22.9 ± 3.2	hexagonal (P6 ₃ mc)
			38.6 ± 4.8	cubic (Fm-3m)
Cd(OAc) ₂ + (Et ₂ NEtSe) ₂	CdSe + CdF ₂	18.3 ± 2.5	22.5 ± 2.9	hexagonal (P6 ₃ mc)
			38.6 ± 4.8	cubic (Fm-3m)
Cd(OAc) ₂ + (Me ₂ NPrSe) ₂	CdSe + CdF ₂	19.1 ± 2.3	13.5 ± 0.6	hexagonal (P6 ₃ mc)
			30.5 ± 1.7	cubic (Fm-3m)



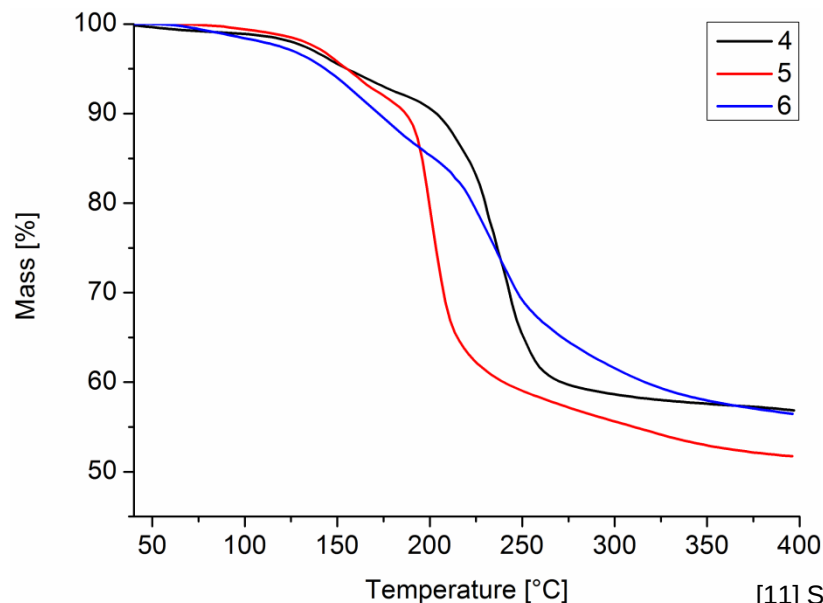
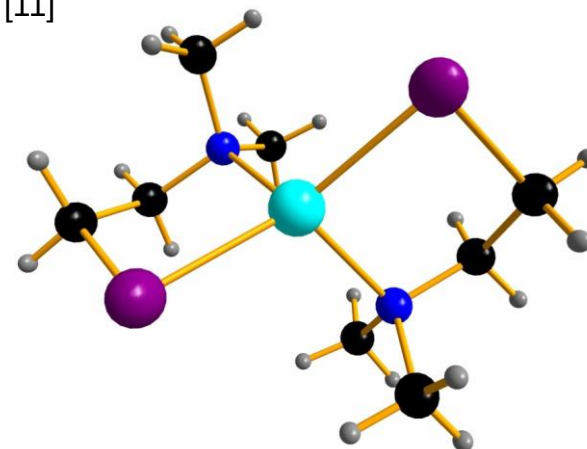
reference: COD-database: 9008863 (CdSe), 9009006 (CdF₂)



ZnSe NPs in [BMIm][BF₄]



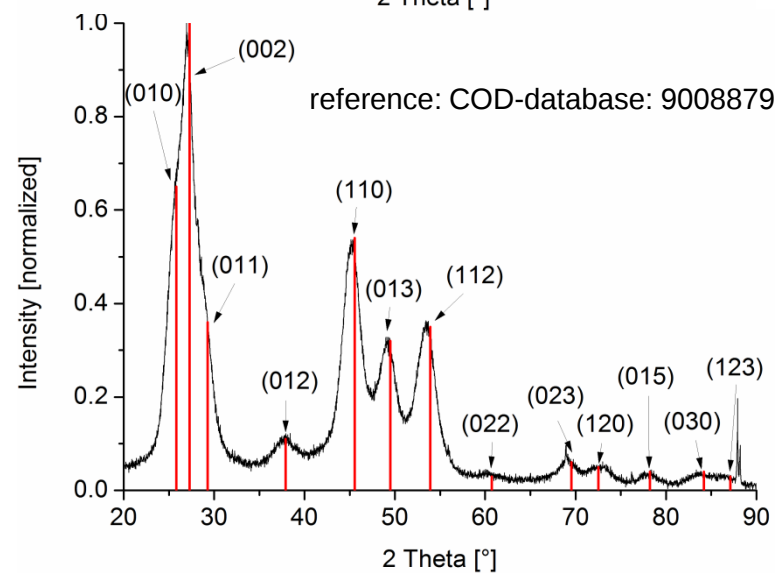
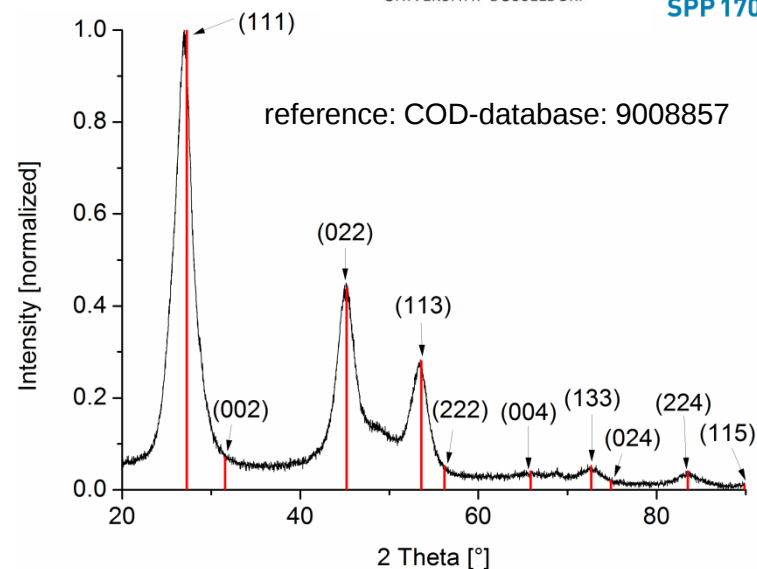
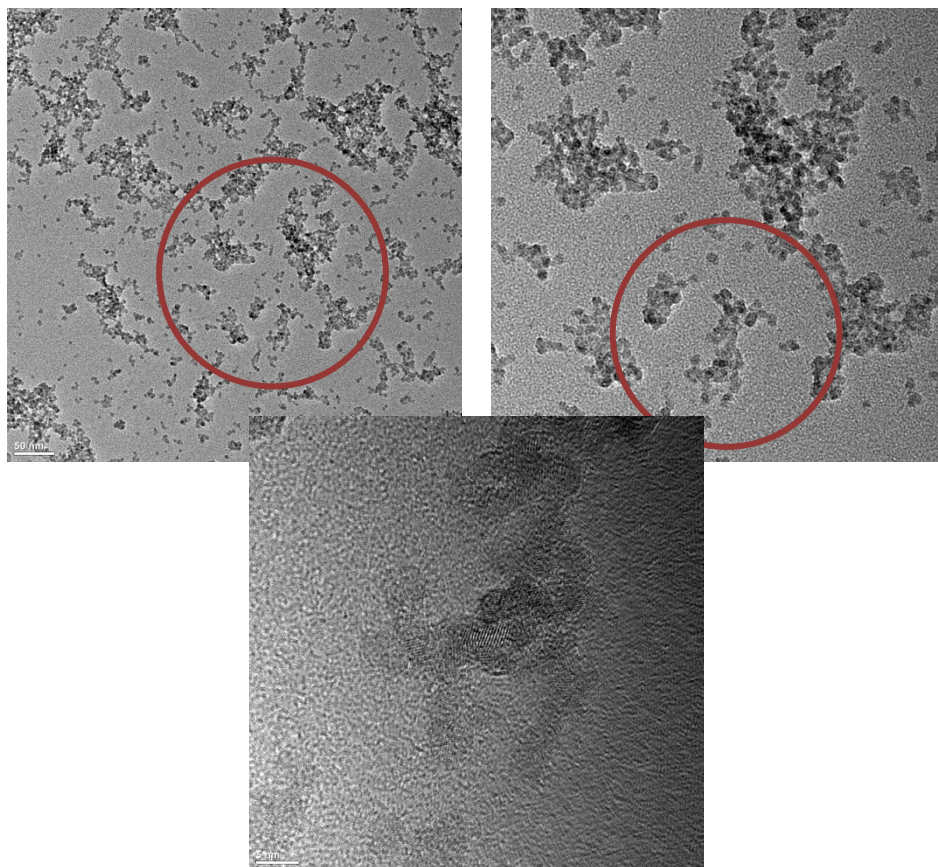
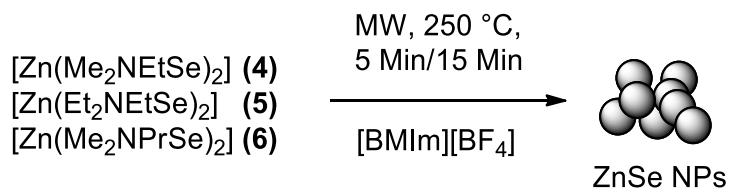
[11]



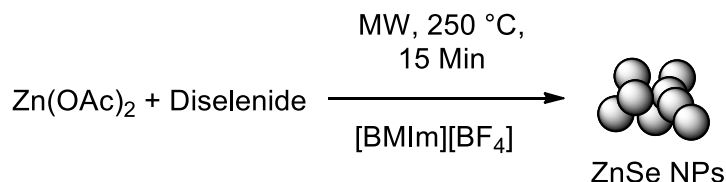
Precursor	Yield [%]	Δm [%]	$\Delta m_{\text{theor.}}$ [%]	Decomp. temp. [°C]	ZnSe crystal system ^a
4	78	43	39	220	hexagonal P6 ₃ mc
5	35	48	45	210	hexagonal P6 ₃ mc
6	67	43	43	215	cubic F-43m

^a From PXRD analysis of the residue of the thermal analysis (hexagonal ZnSe, reference: COD- database: 9008879; cubic ZnSe, reference: COD-database: 9008857)

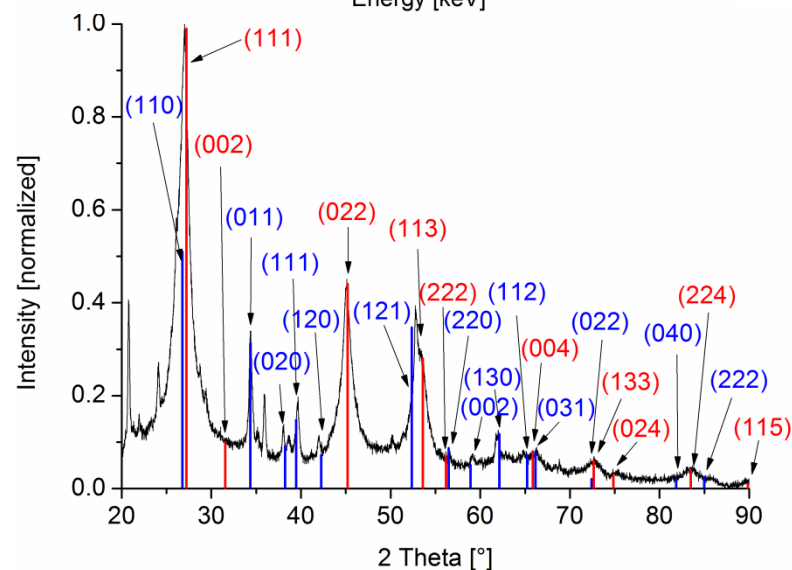
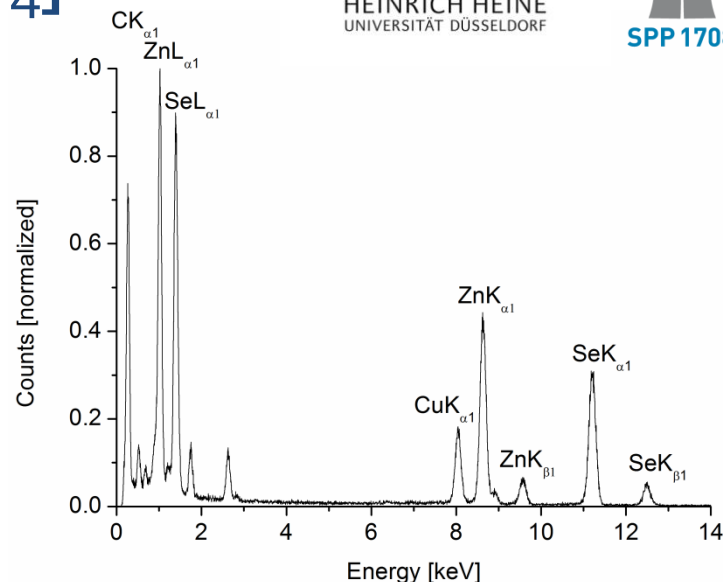
ZnSe NPs in in [BMIm][BF₄]



ZnSe NPs in [BMIm][BF₄]



Precursor	NPs	Ø-NPs TEM [nm]	Ø-NPs PXRD [nm]	crystal system
4 (5min)	ZnSe	7.0 ± 1.9	4.0 ± 0.8	hexagonal (P6 ₃ mc)
5 (5min)	ZnSe	4.7 ± 1.3	4.3 ± 0.4	cubic (F-43m)
6 (5min)	ZnSe	4.0 ± 0.9	4.3 ± 0.5	cubic (F-43m)
4 (15min)	ZnSe	5.0 ± 2.3	4.2 ± 0.4	cubic (F-43m)
5 (15 min)	ZnSe	4.4 ± 1.1	4.8 ± 1.0	cubic (F-43m)
6 (15 min)	ZnSe	4,7 ± 2.1	4.5 ± 0.7	cubic (F-43m)
Zn(OAc) ₂ + (Me ₂ NEtSe) ₂	ZnSe	-	6.2 ± 0.8	cubic (F-43m)
Zn(OAc) ₂ + (Et ₂ NEtSe) ₂	ZnSe + ZnF ₂	-	5.8 ± 1.9 13.2 ± 0.8	cubic (F-43m) cubic (Fm-3m)
Zn(OAc) ₂ + (Me ₂ NPrSe) ₂	ZnSe	-	5.4 ± 0.5	cubic (F-43m)



Conclusions and Outlook

Conclusions:

- Hexagonal CdSe NPs (10 – 27 nm)
- Hexagonal and cubic ZnSe NPs (4 – 5 nm)
- No further stabilizing agents necessary
- Minor role of the ligandsystem and different decomposition times

Outlook:

- Synthesis of CdTe, ZnTe, CdZnSe₂, CdZnSeTe, and CdZnTe₂ in [BMIm][BF₄] and immobilization on TRGO
- Synthesis of other Semiconductor-NPs in ionic liquids and
- Optical and electronic measurements of the synthesized particles

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